Docket No. 010443

Declaration and Power of Attorney For Patent Application English Language Declaration

0 0

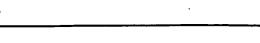
As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Method of Measuring the Two-Dimensional Potential Distribution in CMOS Semiconductor Components

the specification of	which		
(check one)			
is attached here is attached here	eto.		
u was filed on		as United States Application No.	or PCT Internationa
Application Nur	nher		
and was amend	ded on		***************************************
		(if applicable)	
-	I have reviewed and unders s, as amended by any amer	tand the contents of the above independent referred to above.	dentified specificatior
		ed States Patent and Trademark as defined in Title 37, Code of	
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's	e material to patentability a eign priority benefits under any foreign application(s) fo onal application which des v and have also identified b		Section 119(a)-(d) of the than the Unite foreign application for
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's	e material to patentability a eign priority benefits under any foreign application(s) for onal application which des wand have also identified be a certificate or PCT Internation h priority is claimed.	Title 35, United States Code, or patent or inventor's certificate ignated at least one country celow, by checking the box, any	Section 119(a)-(d) of the than the Unite foreign application for
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's application on which	e material to patentability a eign priority benefits under any foreign application(s) for onal application which des wand have also identified be a certificate or PCT Internation h priority is claimed.	Title 35, United States Code, or patent or inventor's certificate ignated at least one country celow, by checking the box, any	Federal Regulations Section 119(a)-(d) of the control of the contr
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's application on which Prior Foreign Applies	e material to patentability a eign priority benefits under any foreign application(s) for onal application which des wand have also identified be a certificate or PCT Internation th priority is claimed.	Title 35, United States Code, or patent or inventor's certificate ignated at least one country celow, by checking the box, any onal application having a filing of	Section 119(a)-(d) of the control of
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's application on which Prior Foreign Application 198 37 490.9 (Number)	e material to patentability a eign priority benefits under any foreign application(s) for onal application which design and have also identified by and have also identified by certificate or PCT Internation priority is claimed. Cation(s) Germany (Country)	Title 35, United States Code, or patent or inventor's certificate ignated at least one country celow, by checking the box, any onal application having a filing control of the country of	Section 119(a)-(d) of the control of
known to me to be Section 1.56. I hereby claim for Section 365(b) of any PCT Internation States, listed below patent or inventor's application on which Prior Foreign Applied 198 37 490.9	e material to patentability a eign priority benefits under any foreign application(s) for analymetric application which designed application which designed by and have also identified by certificate or PCT Internation high priority is claimed. Cation(s) Germany	Title 35, United States Code, or patent or inventor's certificate ignated at least one country of elow, by checking the box, any onal application having a filing of	Federal Regulations Section 119(a)-(d) of the control of the cont



4	V	

1	hereby	claim	the	benefit	under	3£	U.S.C.	Section	119(e)	of	any	United	States	provisiona
а	pplicatio	n(s) lis	ted b	elow:										

N/A	
(Application Serial No.)	(Filing Date)
(Application Serial No.)	(Filing Date)
(Application Serial No.)	(Filing Date)

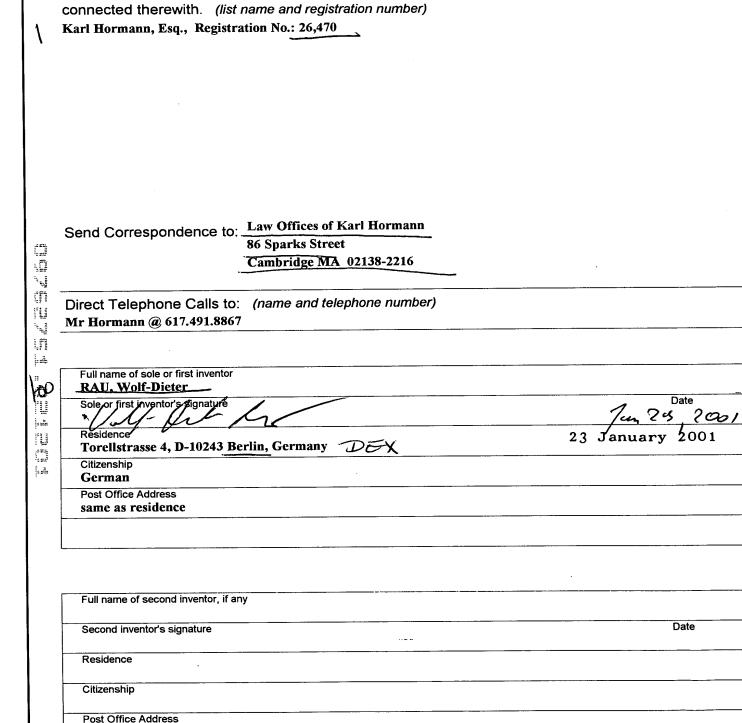
I hereby claim the benefit under 3₹ U. S. C. Section 120 of any United States application(s), or Section 36₹(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 3₹ U.S.C. Section 112, I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, C. F. R., Section 1.₹6 which became available between the filing date of the prior application and the national or PCT International filing date of this application:

PCT/DE99/02380	30 July 1999	Pending		
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)		
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)		
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)		

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Form PTO-SB-01 (6-95) (Modified)

Patent and Trademark Office-U.S. DEPARTMENT OF COMME



POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office

VERIFIED STATEMENT (DECLARATION) CLAIMING SMALL ENTITY STATUS (37 CFR 1.9(f) AND 1.27 (c)) - SMALL BUSINESS CONCERN Docket No. 010443						
Seria	No.	Filing Date 12 February 2001	Patent No.	ls 	ssue Date	
Applicant/ R	AU, Wolf-Diete	er	•			
Invention: I	Method of Meas	suring the Two-Dimensional Pot	ential Distribution of CMOS Se	miconducto	r Components	
NAME OF CADDRESS CONTROLS OF TITLE 3 does not excise the average temporary beither, direct controls or hereby de	official of the significant of t	P GmbH Innovations for High R Im Technologiepark 25, D-152 Dove-identified small business roduced in 37 CFR 1.9(d), for es Code, in that the number of this. For purposes of this statement of the pay periods of the fist, one concern controls or has a control both.	ered to act on behalf of the cor <u>Performance Microelectronics I</u>	astitut fuer in a siness concees under soluding those yees of the long a full-traffiliates of a third affiliates of a third affiliates.	cern as defined in Section 41(a) and se of its affiliates business concertime, part-time of each other where dispartly or parties	
concern ider						
	•	on filed herewith with title as lis	sted above.			
	•	on filed herewith with title as list identified above.	sted above.			

If the rights held by the above-identified small business concern are not exclusive, each individual, concern or organization having rights to the invention is listed on the next page and no rights to the invention are held by any person, other than the inventor, who could not qualify as an independent inventor under 37 CFR 1.9(c) or by any concern which would not qualify as a small business concern under 37 CFR 1.9(d) or a nonprofit organization under 37 CFR 1,9(e).

SIGNATURE;

Each person, concern or organization to which I have assigned, granted, conveyed, or licensed or am under an obligation under contract or law to assign, grant, convey, or license any rights in the invention is listed below: no such person, concern or organization exists. each such person, concern or organization is listed below. **FULL NAME ADDRESS** Nonprofit Organization Small Business Concern Individual **FULL NAME ADDRESS** Nonprofit Organization Individual Small Business Concern **FULL NAME ADDRESS** Nonprofit Organization Individual Small Business Concern **FULL NAME ADDRESS** Small Business Concern Nonprofit Organization Individua! Separate verified statements are required from each named person, concern or organization having rights to the invention averring to their status as small entities. (37 CFR 1.27) I acknowledge the duty to file, in this application or patent, notification of any change in status resulting in loss of entitlement to small entity status prior to paying, or at the time of paying, the earliest of the issue fee or any maintenance fee due after the date on which status as a small entity is no longer appropriate. (37 CFR 1.28(b)) I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application, any patent issuing thereon, or any patent to which this verified statement is directed. NAME OF PERSON SIGNING: Abbas Ourmazd Franz Weinl TITLE OF PERSON SIGNING General Manager General Manager OTHER THAN OWNER: ADDRESS OF PERSON SIGNING: IHP GmbH Innovations for High Performance Microelectronics Institut fuer innovative Mikroelektronik Im Technologiepark 25 D-15236 Frankfurt /Oder, Germany

DATE: 7e6. 8, 2001